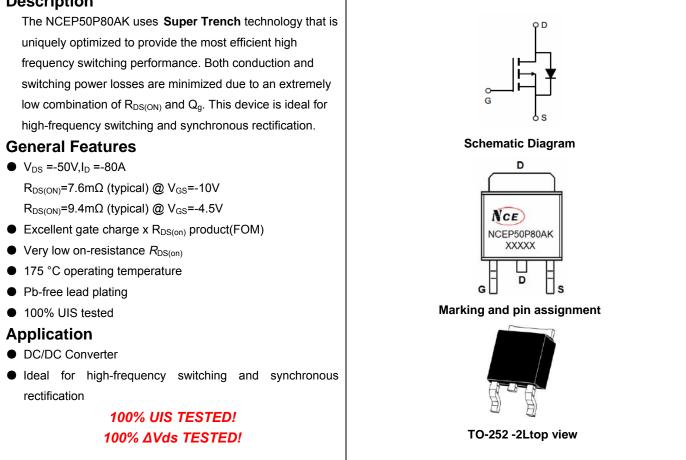


NCE P-Channel Super Trench Power MOSFET





Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP50P80AK	NCEP50P80AK	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_c=25[°]Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-50	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	-80	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	-56	A
Pulsed Drain Current	I _{DM}	-300	A
Maximum Power Dissipation	PD	140	W
Derating factor		0.93	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	720	mJ
Operating Junction and Storage Temperature Range	T_{J},T_{STG}	-55 To 175	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{ejc}	1.07	°C/W	1
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Electrical Characteristics (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	····			•		<u>.</u>
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-50		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-50V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.0		-2.2	V
Drain Source On State Desistance	Р	V _{GS} =-10V, I _D =-20A	-	7.6	9	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =-4.5V, I _D =-20A	-	9.4	11.8	mΩ
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-20A	-	35	-	S
Dynamic Characteristics (Note4)	····					<u>.</u>
Input Capacitance	C _{lss}	V _{DS} =-25V,V _{GS} =0V,	-	3445	-	PF
Output Capacitance	C _{oss}		-	1155	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	22	-	PF
Switching Characteristics (Note 4)	····			•		<u> </u>
Turn-on Delay Time	t _{d(on)}		-	12.5	-	nS
Turn-on Rise Time	tr	V _{DD} =-25V,I _D =-20A	-	5	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =-10V,R _G =1.6Ω	-	45	-	nS
Turn-Off Fall Time	t _f		-	8	-	nS
Total Gate Charge	Qg	(1 - 25)(1 - 20)	-	38.5	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-25V,I _D =-20A,	-	8	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-10V	-	6.5	-	nC
Drain-Source Diode Characteristics				•		
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-20A	-		-1.2	V
Diode Forward Current (Note 2)	I _S		-	-	-80	А
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =-20A	-		30	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-		75	nC
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Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

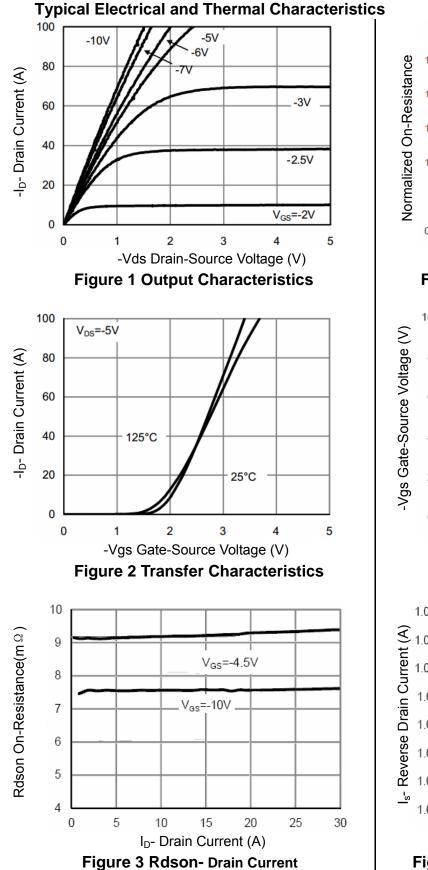
2. Surface Mounted on FR4 Board, t \leq 10 sec.

3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.

4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ C$,V_{DD}=-25V,V_G=-10V,L=0.5mH,Rg=25\Omega





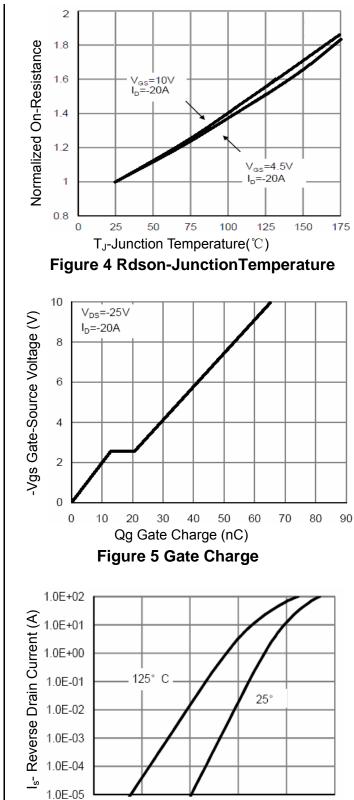


Figure 6 Source- Drain Diode Forward

0.4

Vsd Source-Drain Voltage (V)

0.6

0.8

0.0

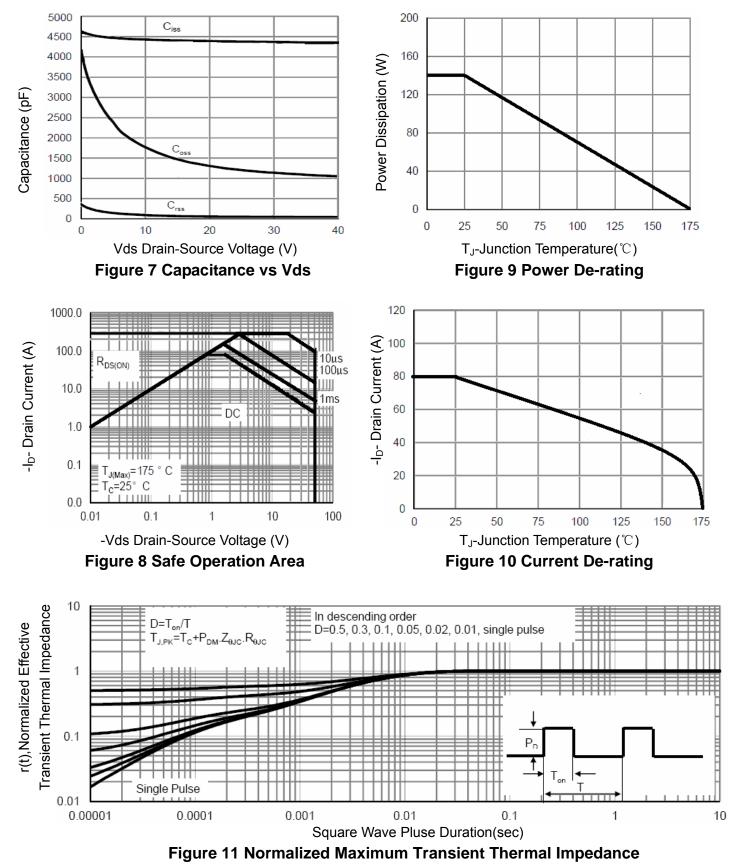
0.2

1.0



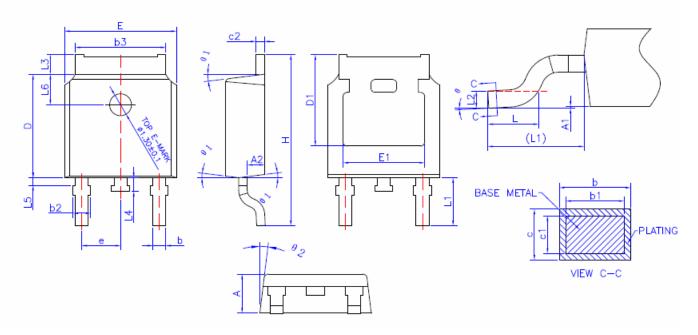
http://www.ncepower.com

NCEP50P80AK





TO-252 Package Information



COMMON DIMENSIONS (UNITS OF MEASURE =MILLIMETER)

SYMBOL	MIN	NOM	MAX	
А	2.20	2.30	2.38	
A1	0	—	0,10	
A2	0,90	1.01	1,10	
b	0.72	—	0.85	
b1	0.71	0.76	0.81	
b2	0,72	—	0,90	
b3	5,13	5,33	5,46	
с	0.47	—	0.60	
c1	0.46	0.51	0.56	
c2	0,47	—	0,60	
D	6,00	6,10	6,20	
D1	5.25	—		
E	6.50	6.60	6.70	
E1	4,70	—		
e	2,186	2,286	2,386	
Н	9.80	10.10	10.40	
L	1.40	1.50	1.70	
L1	2,90 REF			
L2	0.508 BSC			
L3	0.90	—	1.25	
L4	0.60	0.80	1.00	
L5	0,15	—	0,75	
L6	1,80 REF			
θ	0°	—	8°	
θ1	5°	7°	9°	
θ2	5°	7°	9°	



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